

**1. Modify the following text so that the statement is true.**

When the electron concentration is much larger than the holes concentration the semiconductor is called ( **n-p** ) type.

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**2. Consider a light wave traveling in a medium of pure Si. The wavelength of the light is 2.15  $\mu\text{m}$  and the refractive index at this wavelength is 3.45. Calculate the phase velocity of the light wave.**

$$v = \frac{c}{n} = \frac{3 \cdot 10^8 \text{ m/s}}{3.45} = 8.7 \cdot 10^7 \text{ m/s}$$

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**3. Consider a ray of light traveling in a medium of refractive index  $n_1 = 1.43$  becomes incident on a second medium of refractive index  $n_2 = 1.45$ . Calculate the incident angle to have TIR.**

$$\varphi_{lc} = \arcsin\left(\frac{n_2}{n_1}\right) = \arcsin\left(\frac{1.43}{1.45}\right) = 80.47^\circ$$

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**4. Calculate the range of wavelengths not absorbed by Silicon (Si). The bandgap of Si = 1.11 eV.**

$$\lambda < h \frac{c}{E_g(\text{Si})} = \frac{1.24 \text{ eV}\mu\text{m}}{1.11 \text{ eV}} = 1.127 \mu\text{m}$$

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**5. Fill the table indicating the color of light associated to the wavelength values**

wavelength	color
400 nm	blue
550 nm	green
600 nm	orange
700 nm	red

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**6. List three basic parameters of fibre optics that justify its application in data transmission systems.**

1. High Bandwidth
2. Low cost and weigh
3. Low attenuation and dispersion

**7. Modify the following text so that the statement is true.**

Laser diodes are based on the ( **stimulated** / ~~spontaneous~~ ) emission principle.

**8. Fill the table indicating one application for each one of the optoelectronic devices cited on the first row.**

wavelength	application
LEDs	Lighting
Solar cells	Generation of electric energy
Laser diodes	Optical data storage
Photodiodes	Light sensing

**9. Modify the following text so that the statement is true.**

The electrical conductivity of a metal material ( **decreases** / ~~increases~~ ) with increasing temperature

**10. Modify the following text so that the statement is true.**

A photon is absorbed by a semiconductor if the photon energy is ( **greater** / ~~lower~~ ) than the band gap of the material, Eg.